

## CMOS 8-BIT MICROCONTROLLER

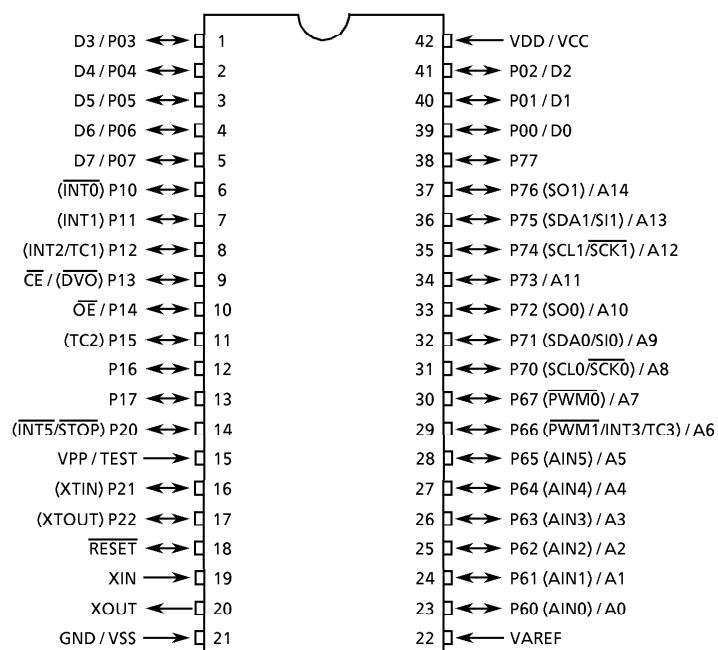
## TMP87PM43N

The 87PM43 is a One-Time PROM microcontroller with low-power 256K bits (a 32K bytes program memory) electrically programmable read only memory for the 87CK43/M43 system evaluation. The 87PM43 is pin compatible with the 87CK43/M43. The operations possible with the 87CK43/M43 can be performed by writing programs to PROM. The 87PM43 can write and verify in the same way as the TC57256AD using an adaptor socket BM1163 and an EPROM programmer.

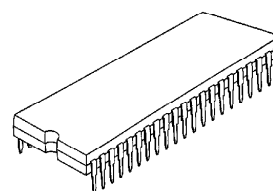
PART No.	OTP	RAM	PACKAGE	Adaptor socket
TMP87PM43N	32K bytes	1K bytes	SDIP42-P-600-1.78	BM1163

## PIN ASSIGNMENTS (TOP VIEW)

SDIP42-P-600-1.78



SDIP42-P-600-1.78



TMP87PM43N



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## PIN FUNCTION

The 87PM43 has two modes: MCU and PROM.

## (1) MCU mode

In this mode, the 87PM43 is pin compatible with the 87CK43/M43 (fix the TEST pin at low level).

## (2) PROM mode

PIN NAME (PROM mode)	INPUT/OUTPUT	FUNCTIONS	PIN NAME (MCU mode)
A14 to A8	Input	PROM address inputs	P76 to P70
A7 to A0			P67 to P60
D7 to D0	I/O	PROM data input/outputs	P07 to P00
$\overline{CE}$	Input	Chip enable signal input (active low)	P13
$\overline{OE}$		Output enable signal input (active low)	P14
VPP	Power supply	+ 12.5 V / 5 V (Program supply voltage)	TEST
VCC		+ 5 V	VDD
GND		0 V	VSS
P11	I/O	PROM mode setting pin. Be fixed at high level.	
P21			
P77			
P12, P10		PROM mode setting pin. Be fixed at low level.	
P17 to P15			
P22, P20			
$\overline{RESET}$			
XIN	Input	Connect an 8 MHz oscillator to stabilize the internal state.	
XOUT	Output		
VAREF	Power supply	0 V (GND)	

## OPERATIONAL DESCRIPTION

The following explains the 87PM43 hardware configuration and operation. The configuration and functions of the 87PM43 are the same as those of the 87CK43/M43, except in that a one-time PROM is used instead of an on-chip mask ROM.

The 87PM43 is placed in the *single-clock* mode during reset. To use the dual-clock mode, the low-frequency oscillator should be turned on by executing [SET (SYSCR2). XTEN] instruction at the beginning of the program.

### 1. OPERATING MODE

The 87PM43 has two modes: MCU and PROM.

#### 1.1 MCU Mode

The MCU mode is activated by fixing the TEST / VPP pin at low level.

In the MCU mode, operation is the same as with the 87CK43/M43 (the TEST / VPP pin cannot be used open because it has no built-in pull-down resistance).

##### 1.1.1 Program Memory

The 87PM43 has a 32K bytes (addresses 8000<sub>H</sub> to FFFF<sub>H</sub> in the MCU mode, addresses 0000<sub>H</sub> to 7FFF<sub>H</sub> in the PROM mode) of program memory (OTP).

When the 87PM43 is used as a system evaluation of the 87CK43/M43, the data is written to the program storage area shown in Figure 1-1.

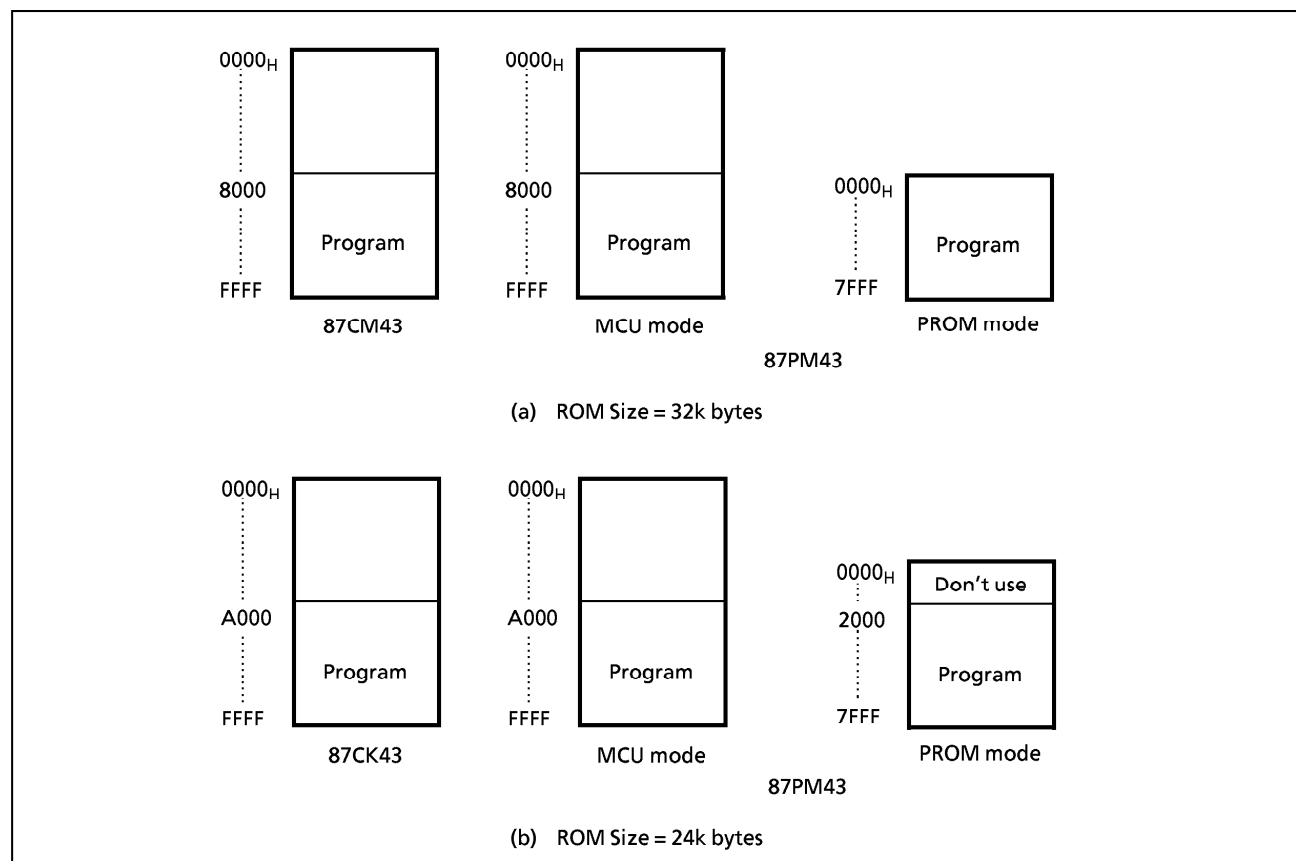


Figure 1-1. Program Memory Area

**Note :** Either write the data FF<sub>H</sub> to the unused area or set the PROM programmer to access only the program storage area.

### 1.1.2 Data Memory

The 87PM43 has an on-chip 1K bytes data memory (static RAM).

### 1.1.3 Input/Output Circuitry

#### (1) Control pins

The control pins of the 87PM43 are the same as those of the 87CK43/M43 except that the TEST pin has no built-in pull-down resistance.

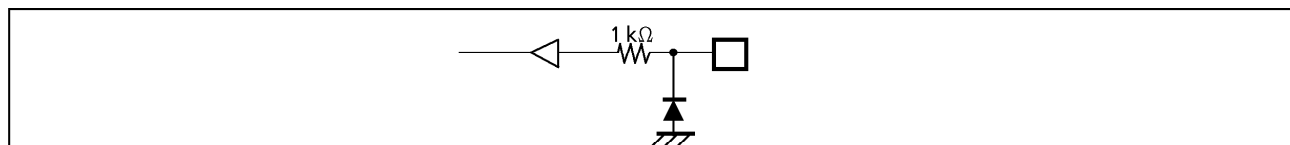


Figure 1-2. TEST Pin

#### (2) I/O ports

The I/O circuitries of 87PM43 I/O ports are the same as the code A type I/O circuits of the 87CK43/M43.

## 1.2 PROM Mode

The PROM mode is activated by setting the TEST,  $\overline{\text{RESET}}$  pin and the ports P17 to P10, P22 to P20, and P77 as shown in Figure 1-3. The PROM mode is used to write and verify programs with a general-purpose PROM programmer. The high-speed programming mode can be used for program operation.

The 87PM43 is not supported an electric signature mode, so the ROM type must be set to TC57256AD.  
Set the adaptor socket switch to "N".

*Note : Please set the high-speed programing mode according to each manual of PROM programmer.*

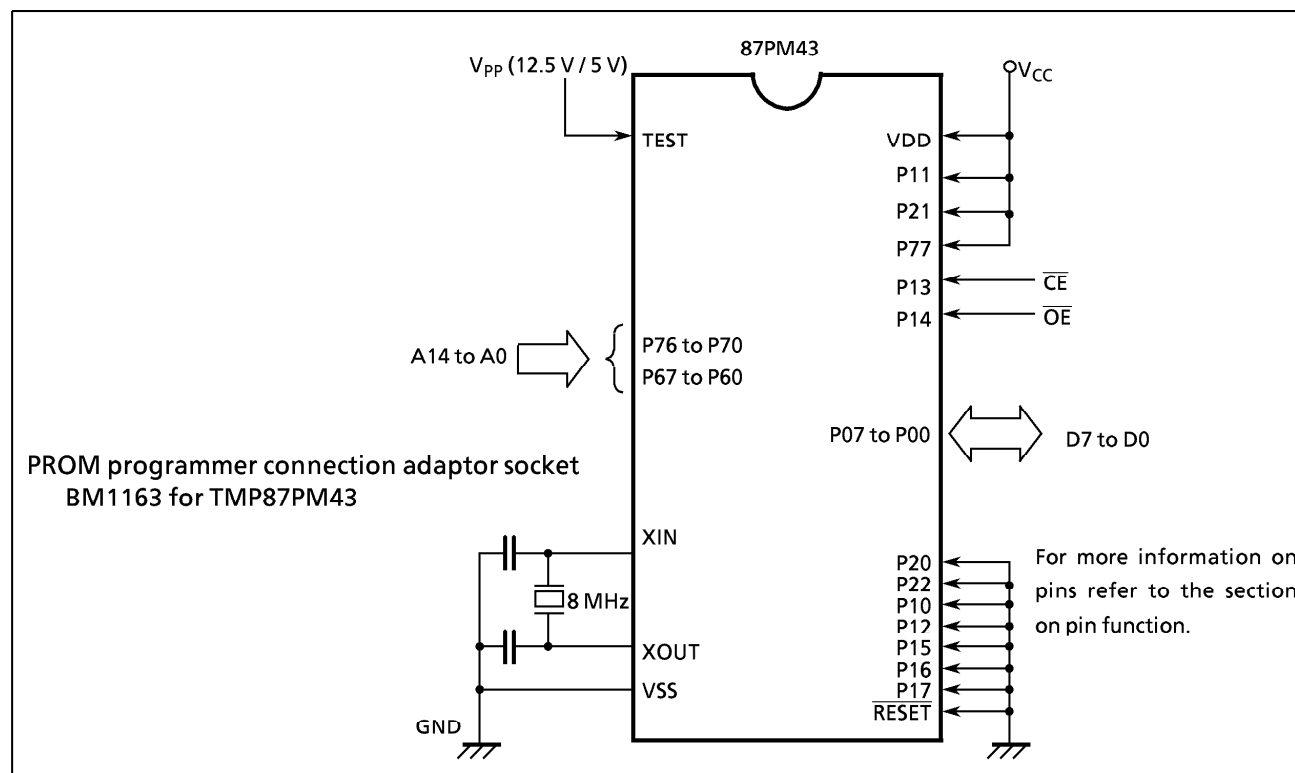


Figure 1-3. Setting for PROM Mode

### 1.2.1 Programming Flowchart (High-speed Programming Mode-I)

The high-speed programming mode is achieved by applying the program voltage (+ 12.5 V) to the VPP pin when  $V_{CC} = 6$  V. After the address and input data are stable, the data is programmed by applying a single 1ms program pulse to the  $\overline{CE}$  input. The programmed data is verified. If incorrect, another 1ms program pulse is applied and then the programmed data is verified. This process should be repeated (up to 25 times) until the program operates correctly. Programming for one address is ended by applying additional program pulse with width 3 times that needed for initial programming (number of programmed times  $\times$  1 ms). After that, change the address and input data, and program as before. When programming has been completed, the data in all addresses should be verified with  $V_{CC} = V_{pp} = 5$  V.

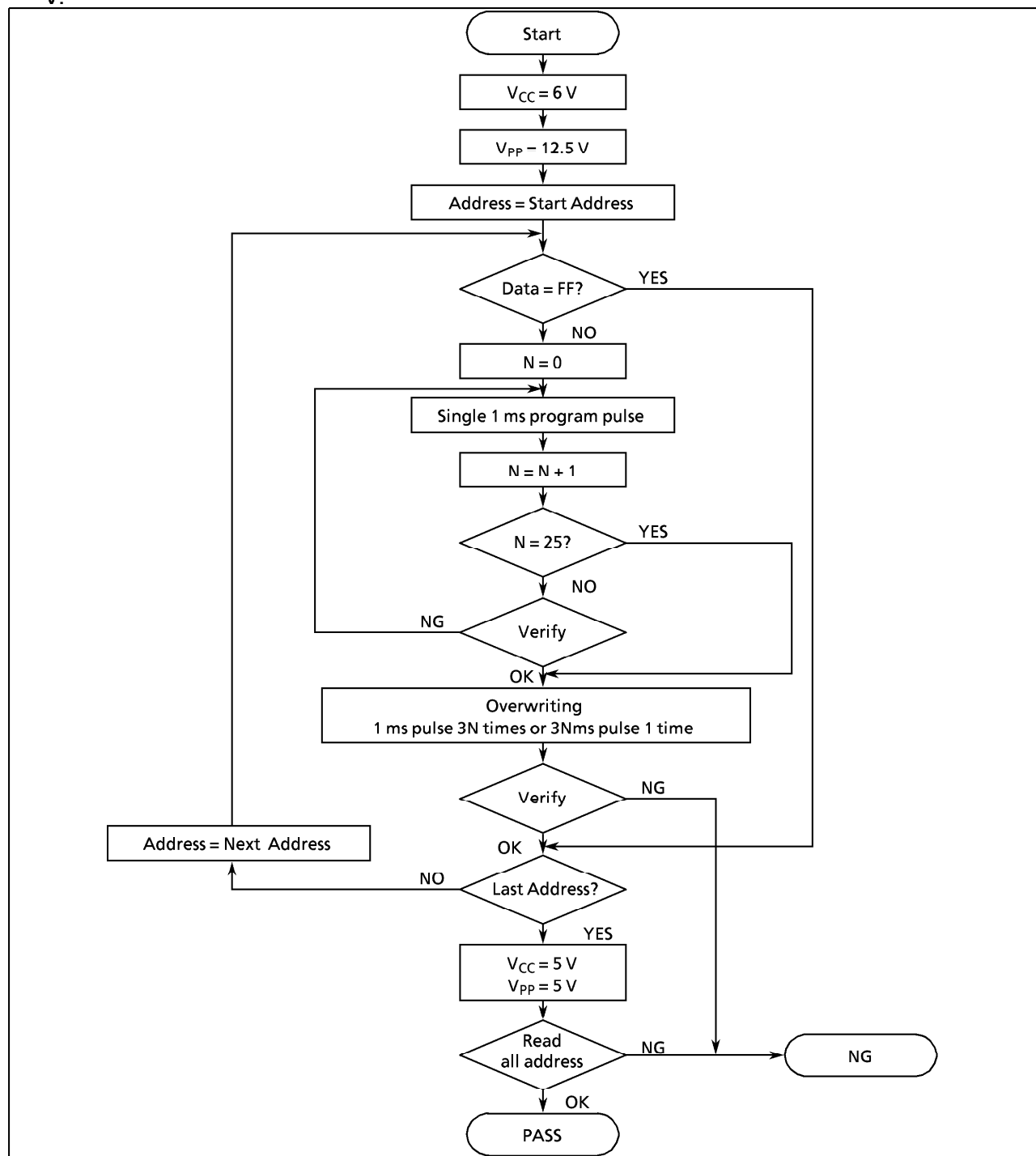


Figure 1-4. Flow chart of High-Speed Programming Mode - I

### 1.2.2 Programming Flowchart (High-speed Programming Mode-II)

The high-speed programming mode is achieved by applying the program voltage (+ 12.75 V) to the Vpp pin when Vcc = 6.25 V. After the address and input data are stable, the data is programmed by applying a single 0.1ms program pulse to the  $\overline{CE}$  input. The programmed data is verified. If incorrect, another 0.1ms program pulse is applied and then the programmed data is verified. This process should be repeated (up to 25 times) until the program operates correctly. After that, change the address and input data, and program as before. When programming has been completed, the data in all addresses should be verified with Vcc = Vpp = 5 V.

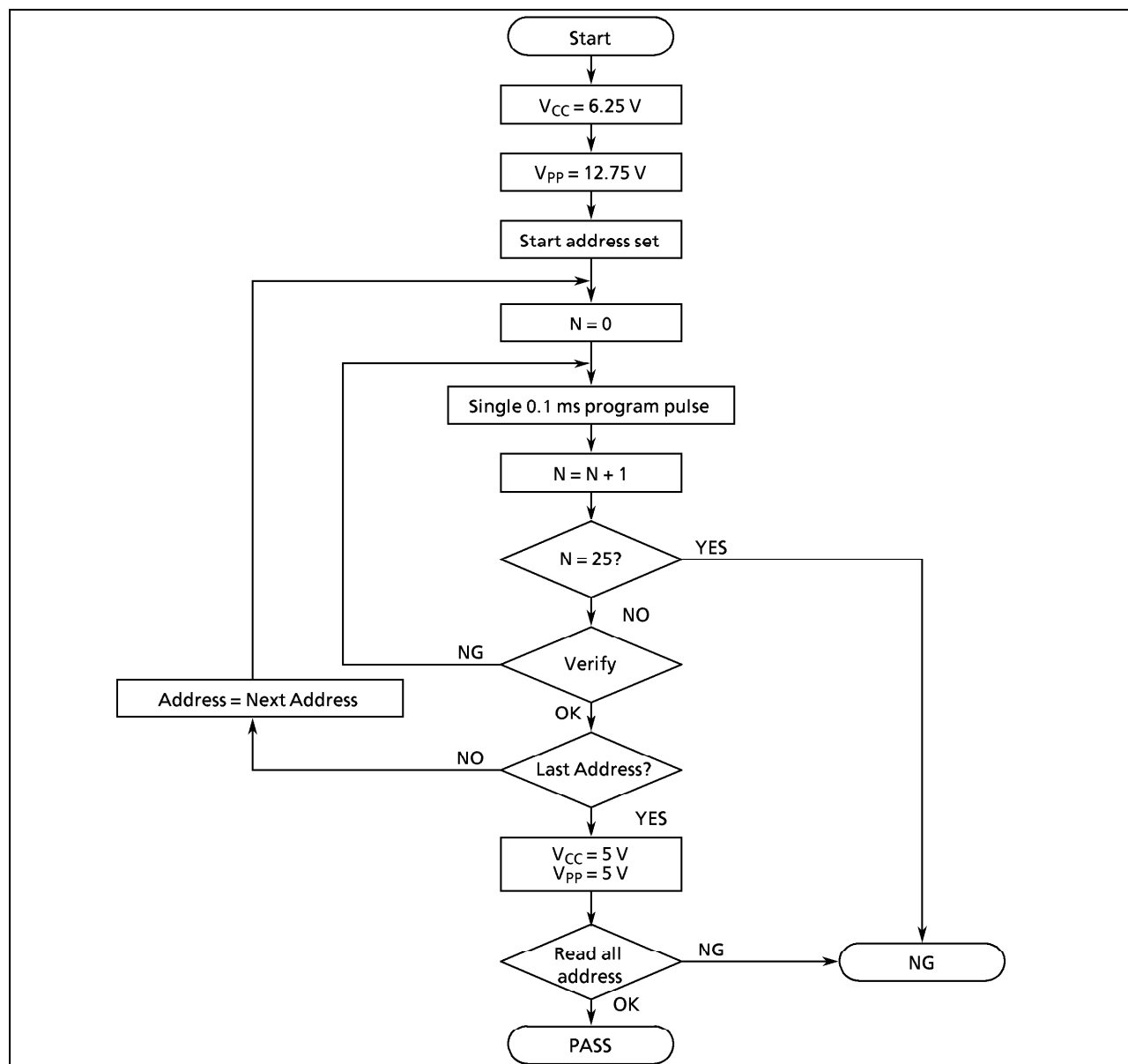


Figure 1-5. Flowchart of High-speed Programming Mode - II

### 1.2.3 Writing Method for General-purpose PROM Program

(1) Adapters

BM1163 : TMP87PM43N

(2) Adapter setting

Switch (SW1) is set to side N.

Switch (SW2) is set to side PM70.

(3) PROM programmer specifying

i) PROM type is specified to TC57256AD.

Writing voltage: 12.5 V (high-speed program I mode)

12.75 V (high-speed program II mode)

ii) Data transfer (copy) (note 1)

In TMP87PM43, EPROM is within the addresses 0000 to 7FFFH. Data is required to be transferred (copied) to the addresses where it is possible to write. The program area in MCU mode and PROM mode is referred to "Program memory area" in Figure 1-1.

Ex. In the block transfer (copy) mode, executed as below.

ROM capacity of 24KB : transferred addresses A000 to FFFFH to addresses 2000 to 7FFFH

iii) Writing address is specified. (note 1)

Start address : 2000H

End address : 7FFFH

(4) Writing

Writing/Verifying is required to be executed in accordance with PROM programmer operating procedure.

*Note 1 : The specifying method is referred to the PROM programmer description. The data in unused area (TMP87CK43) must be specified to FF<sub>H</sub>.*

*Note 2 : When MCU is set to an adapter or the adapter is set to PROM programmer, a position of pin 1 must be adjusted. If the setting is reversed, MCU, the adapter and PROM program is damaged.*

*Note 3 : TMP87PM43 does not support the electric signature mode (hereinafter referred to as "signature"). If the signature is used in PROM program, a device is damaged due to applying 12 V  $\pm$  0.5 V to the address pin 9 (A9). The signature must not be used.*

## ELECTRICAL CHARACTERISTICS

## ABSOLUTE MAXIMUM RATINGS

(V<sub>SS</sub> = 0 V)

PARAMETER	SYMBOL	PINS	RATINGS	UNIT
Supply Voltage	V <sub>DD</sub>		– 0.3 to 6.5	V
Program Voltage	V <sub>PP</sub>	TEST / VPP	– 0.3 to 13.0	V
Input Voltage	V <sub>IN</sub>		– 0.3 to V <sub>DD</sub> + 0.3	V
Output Voltage	V <sub>OUT1</sub>	P0, P1, P21, P22, P60 to 65, RESET, XOUT	– 0.3 to V <sub>DD</sub> + 0.3	V
	V <sub>OUT2</sub>	P20, P66, P67, P7	– 0.3 to V <sub>DD</sub> + 0.3	
Output Current (Per 1 pin)	I <sub>OUT1</sub>	P0, P1, P2, P6, P7	3.2	mA
Output Current (Total)	Σ I <sub>OUT1</sub>	P0, P1, P2, P6, P7	120	mA
Power Dissipation [Topr = 70 °C]	PD		600	mW
Soldering Temperature (time)	I <sub>sld</sub>		260 (10 s)	°C
Storage Temperature	T <sub>stg</sub>		– 55 to 125	°C
Operating Temperature	Topr		– 30 to 70	°C

## RECOMMENDED OPERATING CONDITIONS

(V<sub>SS</sub> = 0 V, Topr = – 30 to 70 °C)

PARAMETER	SYMBOL	PINS	CONDITIONS		Min.	Max.	UNIT
Supply Voltage	V <sub>DD</sub>		f <sub>c</sub> = 8 MHz	NORMAL1, 2 mode	4.5	5.5	V
				IDLE1, 2 mode			
			f <sub>s</sub> = 32.768 kHz	SLOW mode	2.7		
				SLEEP mode			
				STOP mode	2.0		
Input High Voltage	V <sub>IH1</sub>	Except hysteresis input	V <sub>DD</sub> ≥ 4.5 V		V <sub>DD</sub> × 0.70	V <sub>DD</sub>	V
	V <sub>IH2</sub>	Hysteresis input			V <sub>DD</sub> × 0.75		
	V <sub>IH3</sub>		V <sub>DD</sub> < 4.5 V	V <sub>DD</sub> × 0.90			
Input Low Voltage	V <sub>IL1</sub>	Except hysteresis input	V <sub>DD</sub> ≥ 4.5 V		0	V <sub>DD</sub> × 0.30	V
	V <sub>IL2</sub>	Hysteresis input				V <sub>DD</sub> × 0.25	
	V <sub>IL3</sub>		V <sub>DD</sub> < 4.5 V	V <sub>DD</sub> × 0.10			
Clock Frequency	f <sub>c</sub>	XIN, XOUT	V <sub>DD</sub> = 4.5 to 5.5 V		2.0	8.0	MHz
	f <sub>s</sub>	XTIN, XTOUT	V <sub>DD</sub> = 2.7 to 5.5 V		30.0	34.0	kHz

Note : f<sub>c</sub> : The condition of power supply voltage is limited to NORMAL1, NORMAL2, IDLE1, and IDLE2 mode.



## D.C. CHARACTERISTICS

(V<sub>SS</sub> = 0 V, T<sub>opr</sub> = – 30 to 70 °C)

PARAMETER	SYMBOL	PINS	CONDITIONS	Min.	Typ.	Max.	UNIT
Hysteresis Voltage	V <sub>HS</sub>	Hysteresis inputs		–	0.9	–	V
Input Current	I <sub>IN1</sub>	TEST	V <sub>DD</sub> = 5.5 V V <sub>IN</sub> = 5.5 V / 0 V	–	–	± 2	μA
	I <sub>IN2</sub>	Open drain ports, Tri-state ports					
	I <sub>IN3</sub>	RESET, STOP					
Input Resistance	R <sub>IN2</sub>	RESET		100	220	450	kΩ
Output Leakage Current	I <sub>LO</sub>	Sink open drain ports	V <sub>DD</sub> = 5.5 V, V <sub>OUT</sub> = 5.5 V	–	–	2	μA
Output High Voltage	V <sub>OH2</sub>	Tri-state ports	V <sub>DD</sub> = 4.5 V, I <sub>OH</sub> = – 0.7 mA	4.1	–	–	V
Output Low Voltage	V <sub>OL</sub>	Except XOUT	V <sub>DD</sub> = 4.5 V, I <sub>OL</sub> = 1.6 mA	–	–	0.4	V
Supply Current in NORMAL 1, 2 modes	I <sub>DD</sub>		V <sub>DD</sub> = 5.5 V f <sub>c</sub> = 8 MHz f <sub>s</sub> = 32.768 kHz V <sub>IN</sub> = 5.3 V / 0.2 V	–	12	18	mA
Supply Current in IDLE 1, 2 modes				–	4.5	6	
Supply Current in SLOW mode			V <sub>DD</sub> = 3.0 V f <sub>s</sub> = 32.768 kHz V <sub>IN</sub> = 2.8 V / 0.2 V	–	30	60	μA
Supply Current in SLEEP mode				–	15	30	
Supply Current in STOP mode			V <sub>DD</sub> = 5.5 V V <sub>IN</sub> = 5.3 V / 0.2 V	–	0.5	10	μA

Note 1 : Typical values show those at T<sub>opr</sub> = 25 °C, V<sub>DD</sub> = 5 V.Note 2 : Input Current I<sub>IN1</sub>, I<sub>IN3</sub>; The current through resistor is not included, when the input register (pull-up or pull-down) is contained.

## A / D CONVERSION CHARACTERISTICS

(V<sub>SS</sub> = 0 V, V<sub>DD</sub> = 4.5 to 5.5 V, T<sub>opr</sub> = – 30 to 70 °C)

PARAMETER	SYMBOL	CONDITIONS	Min.	Typ.	Max.	UNIT
Analog Reference Voltage	V <sub>AREF</sub>	V <sub>DD</sub> ≥ 4.5 V, V <sub>SS</sub> = 0 V	V <sub>DD</sub> – 1.5	–	V <sub>DD</sub>	V
Analog Reference Voltage Range	ΔV <sub>AREF</sub>		3.0	–	–	V
Analog Input Voltage Range	V <sub>AIN</sub>		V <sub>SS</sub>	–	V <sub>AREF</sub>	V
Analog Supply Current	I <sub>REF</sub>		–	0.5	1.0	mA
Nonlinearity Error		V <sub>DD</sub> = 5.0 V, V <sub>SS</sub> = 0.000 V V <sub>AREF</sub> = 5.000 V	–	–	± 1	LSB
Zero Point Error			–	–	± 1	
Full Scale Error			–	–	± 1	
Total Error			–	–	± 2	

Note 1 : ΔV<sub>AREF</sub> = V<sub>AREF</sub> – V<sub>SS</sub>

Note 2 : Quantizing error is not contained in those errors.

## A.C. CHARACTERISTICS

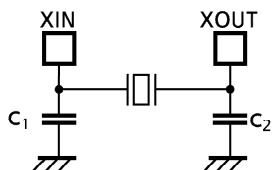
(V<sub>SS</sub> = 0 V, V<sub>DD</sub> = 4.5 to 5.5 V, T<sub>opr</sub> = – 30 to 70 °C)

PARAMETER	SYMBOL	CONDITIONS	Min.	Typ.	Max.	UNIT
Machine Cycle Time	t <sub>cy</sub>	In NORMAL1, 2 modes	0.5	–	10	μs
		In IDLE1, 2 modes				
		In SLOW mode	117.6	–	133.3	
		In SLEEP mode				
High Level Clock Pulse Width	t <sub>WCH</sub>	For external clock operation (XIN input), f <sub>c</sub> = 8 MHz	62.5	–	–	ns
Low Level Clock Pulse Width	t <sub>WCL</sub>					
High Level Clock Pulse Width	t <sub>WSH</sub>	For external clock operation (XTIN input), f <sub>s</sub> = 32.768 kHz	14.7	–	–	μs
Low Level Clock Pulse Width	t <sub>WSL</sub>					

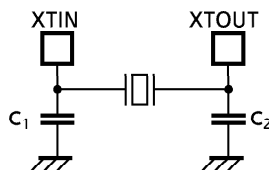
## RECOMMENDED OSCILLATING CONDITIONS

(V<sub>SS</sub> = 0 V, V<sub>DD</sub> = 4.5 to 5.5 V, T<sub>opr</sub> = – 30 to 70 °C)

PARAMETER	Oscillator	Oscillation Frequency	Recommended Oscillator	Recommended Constant	
				C <sub>1</sub>	C <sub>2</sub>
High-frequency Oscillation	Ceramic Resonator	8 MHz	KYOCERA KBR8.0M	30 pF	30 pF
		4 MHz	KYOCERA KBR4.0MS		
			MURATA CSA4.00MG		
	Crystal Oscillator	8 MHz	TOYOCOM 210B 8.0000	20 pF	20 pF
		4 MHz	TOYOCOM 204B 4.0000		
Low-frequency Oscillation	Crystal Oscillator	32.768 kHz	NDK MX-38T	15 pF	15 pF



(1) High-frequency Oscillation

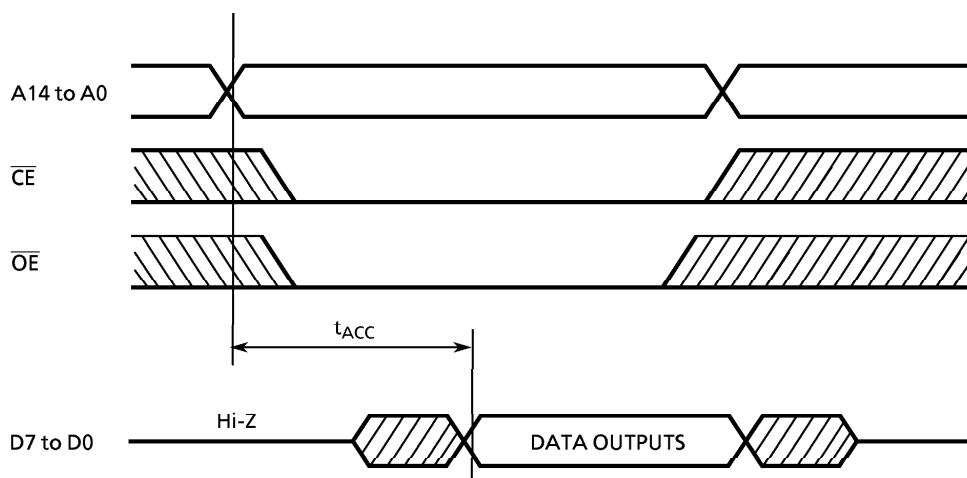


(3) Low-frequency Oscillation

**Note :** An electrical shield by metal shield plate on the surface of the IC package should be recommendable in order to prevent the device from the high electric fieldstress applied from CRT (Cathode Ray Tube) for continuous reliable operation.

D.C./A.C. CHARACTERISTICS (PROM mode) ( $V_{SS} = 0\text{ V}$ )(1) READ OPERATION ( $T_{opr} = 0 \text{ to } 70\text{ }^{\circ}\text{C}$ )

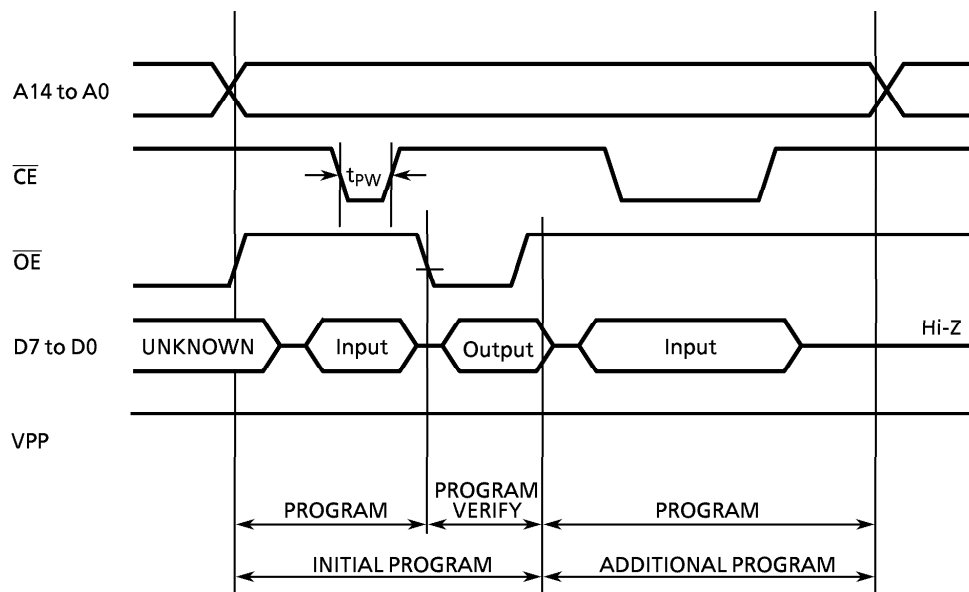
PARAMETER	SYMBOL	CONDITIONS	Min.	Typ.	Max.	UNIT
Input High Voltage	$V_{IH4}$		$V_{CC} \times 0.7$	—	$V_{CC}$	V
Input Low Voltage	$V_{IL4}$		0	—	$V_{CC} \times 0.12$	V
Power Supply Voltage	$V_{CC}$		4.75	—	6.0	V
Program Power Supply Voltage	$V_{PP}$					
Address Access Time	$t_{ACC}$	$V_{CC} = 5.0 \pm 0.25\text{ V}$	—	$1.5t_{cyc} + 300$	—	ns

Note :  $t_{cyc} = 500\text{ ns}$  at 8 MHz

TIMING WAVEFORMS OF READ OPERATION

(2) HIGH-SPEED PROGRAMMING OPERATION (High-Speed Programming Mode- I ) ( $T_{opr} = 25 \pm 5\text{ }^{\circ}\text{C}$ )

PARAMETER	SYMBOL	CONDITIONS	Min.	Typ.	Max.	UNIT
Input High Voltage	$V_{IH4}$		$V_{CC} \times 0.7$	—	$V_{CC}$	V
Input Low Voltage	$V_{IL4}$		0	—	$V_{CC} \times 0.12$	V
Power Supply Voltage	$V_{CC}$		5.75	6.0	6.25	V
Program Power Supply Voltage	$V_{PP}$		12.0	12.5	13.0	V
Initial Program Pulse Width	$t_{PW}$	$V_{CC} = 6.0\text{ V} \pm 0.25\text{ V}$ $V_{PP} = 12.5 \pm 0.25\text{ V}$	0.95	1.0	1.05	ms



TIMING WAVEFORMS OF PROGRAMMING OPERATION

**Note 1:** When  $V_{CC}$  power supply is turned on or after,  $V_{PP}$  must be increased.

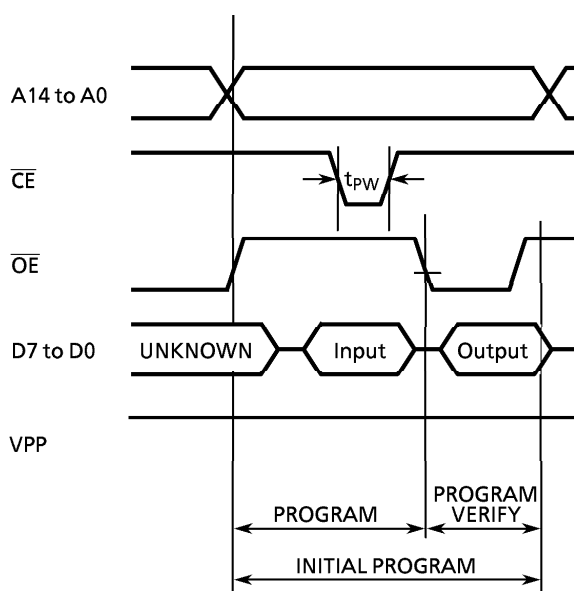
When  $V_{CC}$  power supply is turned off or before,  $V_{PP}$  must be decreased.

**Note 2:** The device must not be set to the EPROM programmer or picked up from it under applying the program voltage ( $12.5\text{ V} \pm 0.5\text{ V}$ ) to the  $V_{PP}$  pin as the device is damaged.

**Note 3:** Be sure to execute the recommended programming mode with the recommended programming adaptor. If a mode or an adaptor except the above, the misoperation sometimes occurs.

(3) HIGH-SPEED PROGRAMMING OPERATION (High-Speed program mode-II) ( $T_{opr} = 25 \pm 5^\circ\text{C}$ )

PARAMETER	SYMBOL	CONDITIONS	Min.	Typ.	Max.	UNIT
Input High Voltage	$V_{IH4}$		$V_{CC} \times 0.7$	—	$V_{CC}$	V
Input Low Voltage	$V_{IL4}$		0	—	$V_{CC} \times 0.12$	V
Supply Voltage	$V_{CC}$		6.00	6.25	6.50	V
Program Supply Voltage	$V_{PP}$		12.50	12.75	13.0	V
Initial Program Pulse Width	$t_{PW}$	$V_{CC} = 6.25 \text{ V} \pm 0.25 \text{ V}$ , $V_{PP} = 12.75 \pm 0.25 \text{ V}$	0.095	0.1	0.105	ms



**Note 1:** When  $V_{CC}$  power supply is turned on or after,  $V_{PP}$  must be increased.

When  $V_{CC}$  power supply is turned off or before,  $V_{PP}$  must be decreased.

**Note 2:** The device must not be set to the EPROM programmer or picked up from it under applying the program voltage ( $12.75 \text{ V} \pm 0.25 \text{ V}$ ) to the  $V_{PP}$  pin as the device is damaged.

**Note 3:** Be sure to execute the recommended programming mode with the recommended programming adaptor. If a mode or an adaptor except the above, the misoperation sometimes occurs.

